NSN 5961-00-116-9020

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-116-9020 **Inclosure Material:** Metal **Overall Length:** 0.330 inches **Overall Diameter:** 0.375 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 350.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 400.00 milliamperes source cutoff current and 150.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No